

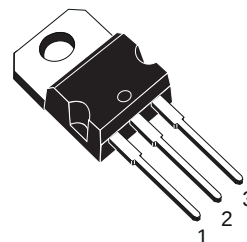
**BU931T**

HIGH VOLTAGE IGNITION COIL DRIVER NPN POWER DARLINGTON TRANSISTOR

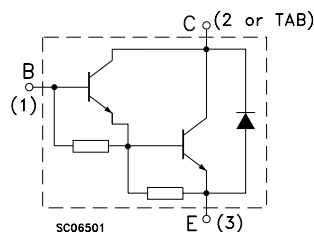
- VERY RUGGED BIPOLAR TECHNOLOGY
- HIGH OPERATING JUNCTION TEMPERATURE

APPLICATIONS

- HIGH RUGGEDNESS ELECTRONIC IGNITIONS

**TO-220**

INTERNAL SCHEMATIC DIAGRAM



ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V_{CES}	Collector-Emitter Voltage ($V_{BE} = 0$)	500	V
V_{CEO}	Emitter-Base Voltage ($I_B = 0$)	400	V
V_{EBO}	Emitter-Base Voltage ($I_C = 0$)	5	V
I_C	Collector Current	10	A
I_{CM}	Collector Peak Current	15	A
I_B	Base Current	1	A
I_{BM}	Base Peak Current	5	A
P_{tot}	Total Dissipation at $T_c = 25\text{ }^{\circ}\text{C}$	125	W
T_{stg}	Storage Temperature	-65 to 175	$^{\circ}\text{C}$
T_j	Max. Operating Junction Temperature	175	$^{\circ}\text{C}$

THERMAL DATA

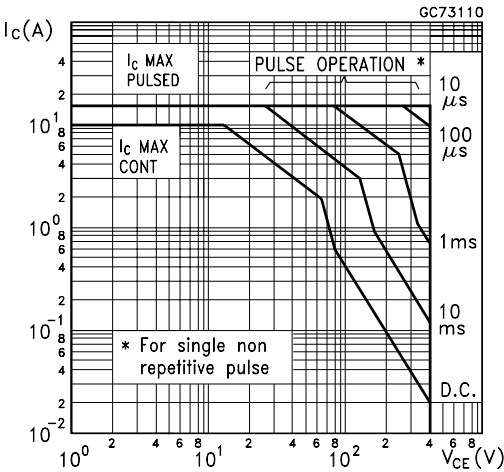
R _{thj-case}	Thermal Resistance Junction-case	Max	1.2	°C/W
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ELECTRICAL CHARACTERISTICS (T_{case} = 25 °C unless otherwise specified)

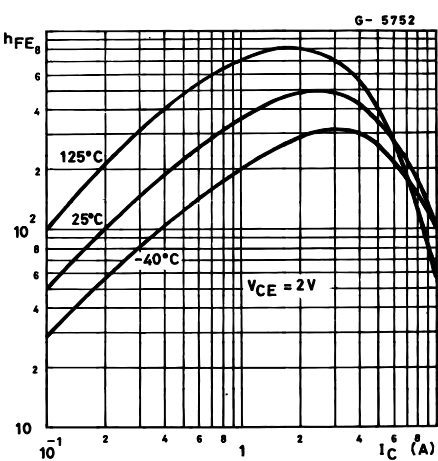
Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
I _{CES}	Collector Cut-off Current (V _{BE} = 0)	V _{CE} = 500 V V _{CE} = 500 V T _C = 125 °C			100 0.5	μA mA
I _{CEO}	Collector Cut-off Current (I _B = 0)	V _{CE} = 450 V V _{CE} = 450 V T _C = 125 °C			100 0.5	μA mA
I _{EBO}	Emitter Cut-off Current (I _C = 0)	V _{EB} = 5 V			20	mA
V _{CEO(SUS)*}	Collector-Emitter Saturation Voltage (I _B = 0)	I _C = 100 mA L = 10 mH I _B = 0 V _{CLAMP} = 400 V (see fig.4)	400			V
V _{CE(sat)*}	Collector-Emitter Saturation Voltage	I _C = 7 A I _B = 70 mA I _C = 8 A I _B = 100 mA			1.6 1.8	V V
V _{BE(sat)*}	Base-Emitter Saturation Voltage	I _C = 7 A I _B = 70 mA I _C = 8 A I _B = 100 mA			2.2 2.4	V V
h _{FE*}	DC Current Gain	I _C = 5 A V _{CE} = 10 V	300			
V _F	Diode Forward Voltage	I _F = 10 A			2.5	V
	Functional Test	V _{CC} = 24 V V _{clamp} = 400 V L = 7 mH (see fig. 1)	8			A
t _s t _f	INDUCTIVE LOAD Storage Time Fall Time	V _{CC} = 12 V V _{clamp} = 300 V L = 7 mH I _C = 7 A I _B = 70 mA V _{BE} = 0 R _{BE} = 47 Ω (see fig. 3)		15 0.5		μs μs

* Pulsed: Pulse duration = 300 μs, duty cycle 1.5 %

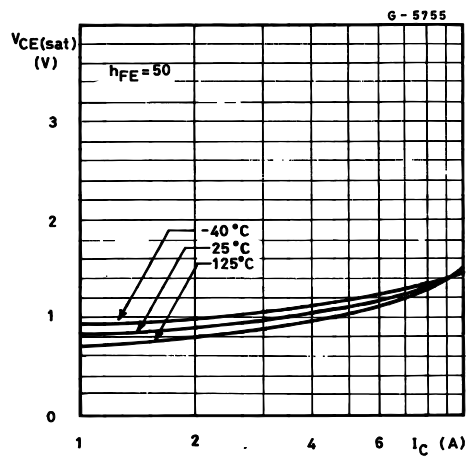
Safe Operating Area



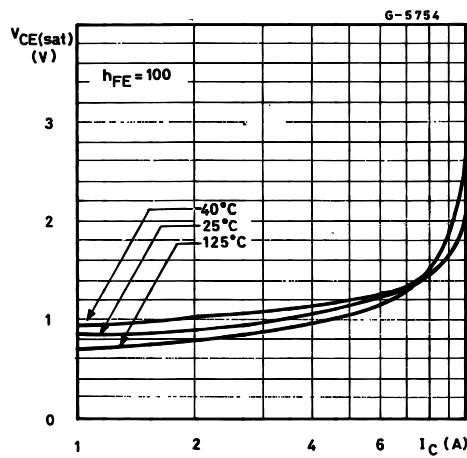
DC Current Gain



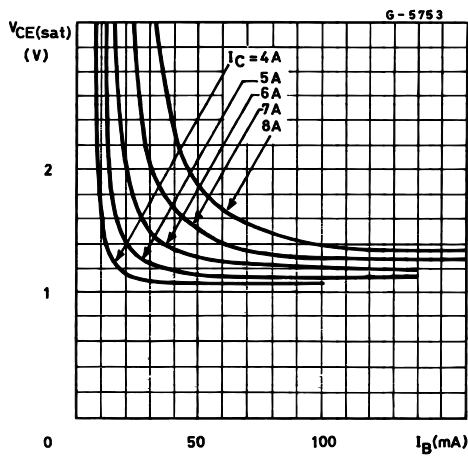
Collector Emitter Saturation Voltage



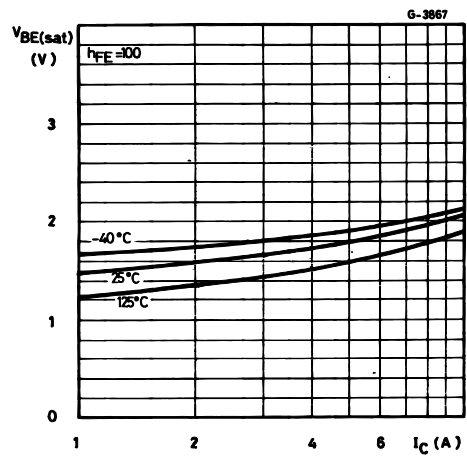
Collector Emitter Saturation Voltage



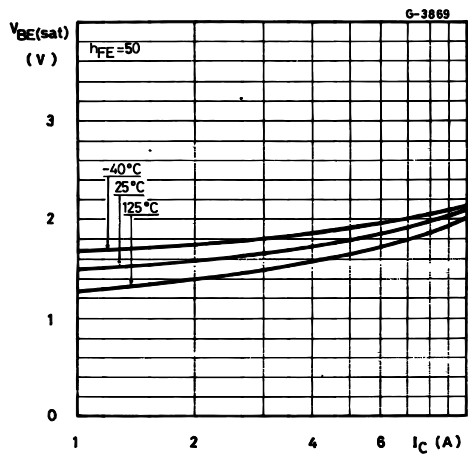
Collector Emitter Saturation Voltage



Base Emitter Saturation Voltage



Base Emitter Saturation Voltage



Switching Time Inductive Load

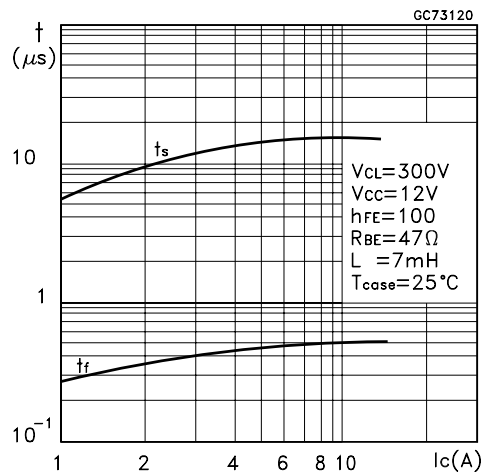


FIGURE 1: Functional Test Circuit

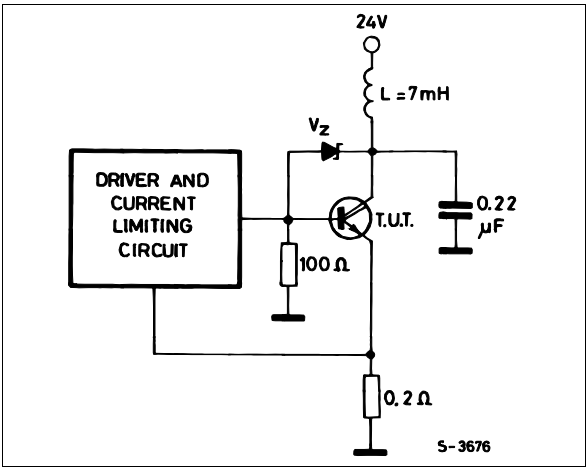


FIGURE 2: Functional Test Waveforms

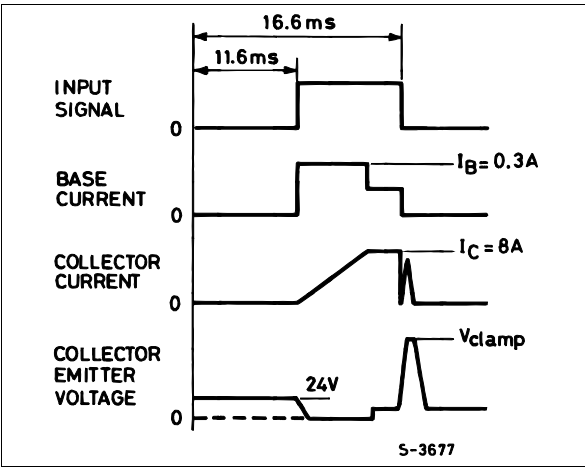


FIGURE 3: Switching Time Test Circuit

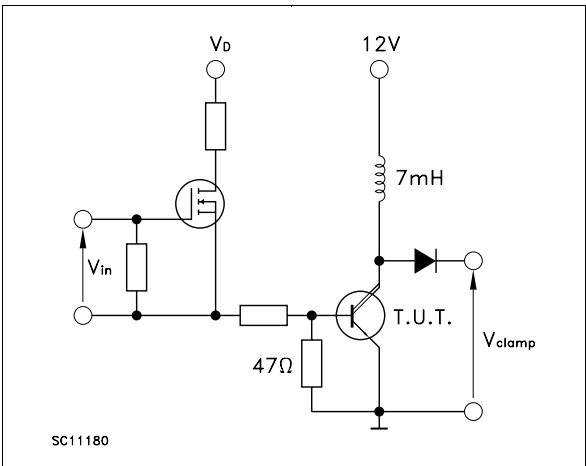
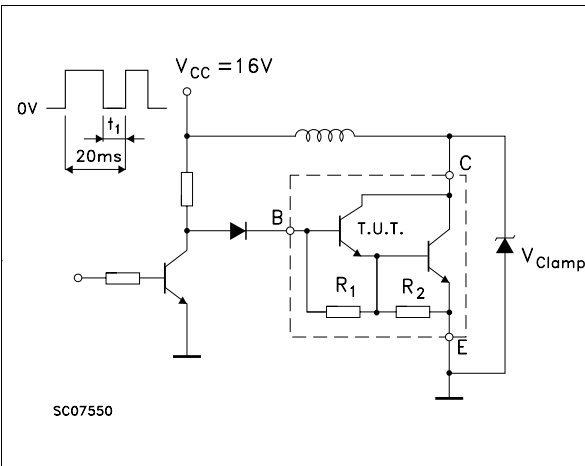
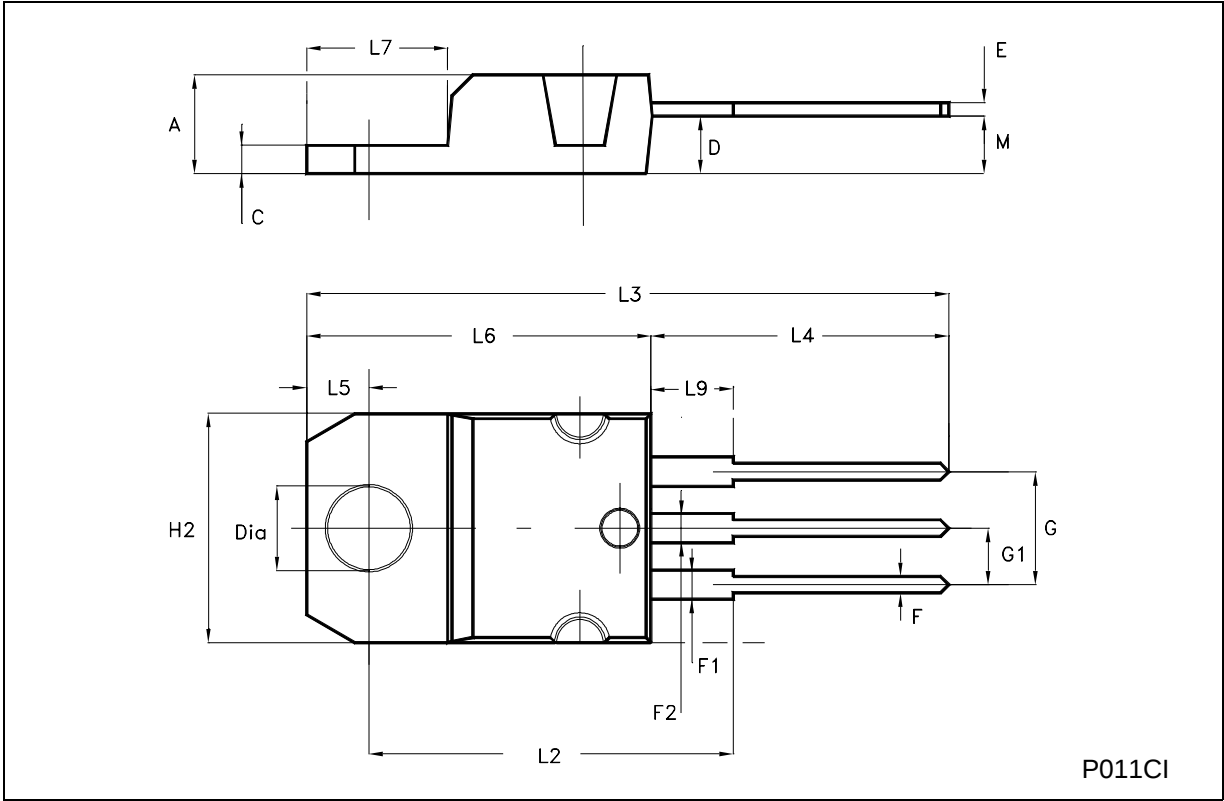


FIGURE 4: Sustaining Voltage Test Circuit



TO-220 MECHANICAL DATA

DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A	4.40		4.60	0.173		0.181
C	1.23		1.32	0.048		0.052
D	2.40		2.72	0.094		0.107
E	0.49		0.70	0.019		0.027
F	0.61		0.88	0.024		0.034
F1	1.14		1.70	0.044		0.067
F2	1.14		1.70	0.044		0.067
G	4.95		5.15	0.194		0.202
G1	2.40		2.70	0.094		0.106
H2	10.00		10.40	0.394		0.409
L2		16.40			0.645	
L4	13.00		14.00	0.511		0.551
L5	2.65		2.95	0.104		0.116
L6	15.25		15.75	0.600		0.620
L7	6.20		6.60	0.244		0.260
L9	3.50		3.93	0.137		0.154
M		2.60			0.102	
DIA.	3.75		3.85	0.147		0.151



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